TOSHIBA Insulated Gate Bipolar Transistor Silicon N Channel IGBT

# GT30J121

### High Power Switching Applications Fast Switching Applications

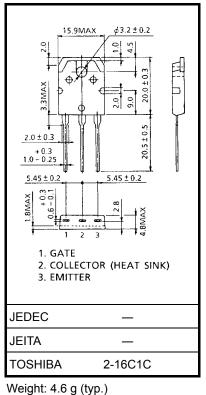
- Fourth-generation IGBT
- Enhancement mode type
- Fast switching (FS): Operating frequency up to 50 kHz (reference) High speed:  $t_f = 0.05 \ \mu s$  (typ.) Low switching loss:  $E_{on} = 1.00 \ mJ$  (typ.)

 $E_{off} = 0.80 \text{ mJ (typ.)}$ 

• Low saturation voltage: VCE (sat) = 2.0 V (typ.)

### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-emitter voltage		V <sub>CES</sub>	600	V	
Gate-emitter voltage		V <sub>GES</sub>	±20	V	
Collector current	DC	Ι <sub>C</sub>	30	A	
	1 ms	I <sub>CP</sub>	60		
Collector power dissipation (Tc = 25°C)		P <sub>C</sub>	170	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



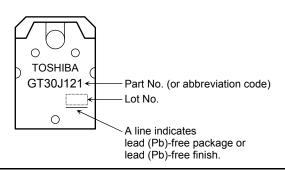
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

### Thermal Characteristics

Characteristics	Symbol	Мах	Unit
Thermal resistance	R <sub>th (j-c)</sub>	0.735	°C/W

#### Marking

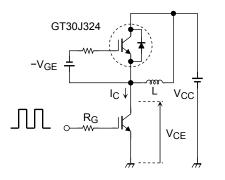


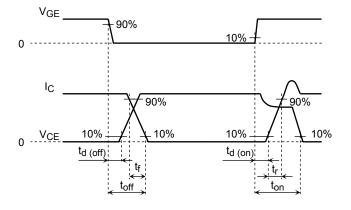
Unit: mm

Electrical Characteristics (Ta = 25°C)

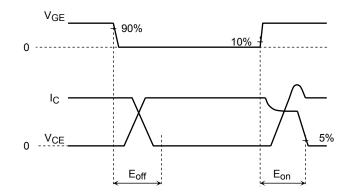
Cha	racteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	urrent	I <sub>GES</sub>	$V_{GE}$ = ±20 V, $V_{CE}$ = 0	_	_	±500	nA
Collector cut-off current		ICES	V <sub>CE</sub> = 600 V, V <sub>GE</sub> = 0	_	_	1.0	mA
Gate-emitter cut-off voltage		V <sub>GE (OFF)</sub>	$I_{C}$ = 3 mA, $V_{CE}$ = 5 V	3.5	_	6.5	V
Collector-emitte	r saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = 30 A, V <sub>GE</sub> = 15 V	—	2.0	2.45	V
Input capacitance		Cies	$V_{CE}$ = 10 V, $V_{GE}$ = 0, f = 1 MHz	—	4650	—	pF
Switching time	Turn-on delay time	t <sub>d (on)</sub>	Inductive Load $V_{CC}$ = 300 V, I <sub>C</sub> = 30 A $V_{GG}$ = +15 V, R <sub>G</sub> = 24 $\Omega$ (Note 1) (Note 2)	_	0.09	—	- µs
	Rise time	tr		_	0.07	_	
	Turn-on time	t <sub>on</sub>			0.24	_	
	Turn-off delay time	<sup>t</sup> d (off)		_	0.30	_	
	Fall time	t <sub>f</sub>		_	0.05	_	
	Turn-off time	t <sub>off</sub>		_	0.43	_	
Switching loss	Turn-on switching loss	E <sub>on</sub>		_	1.00	_	mJ
	Turn-off switching loss	E <sub>off</sub>		_	0.80	—	

Note 1: Switching time measurement circuit and input/output waveforms

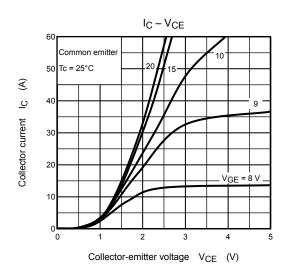


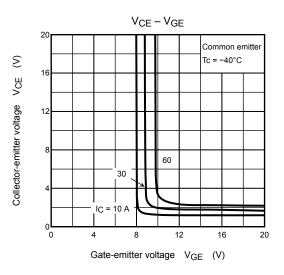


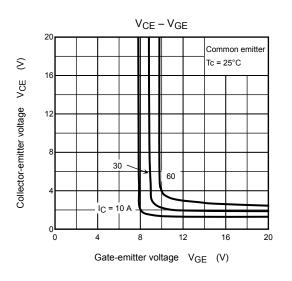
#### Note 2: Switching loss measurement waveforms

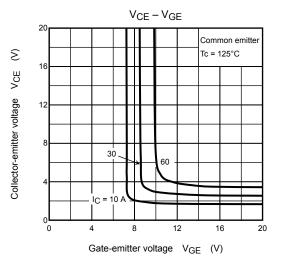


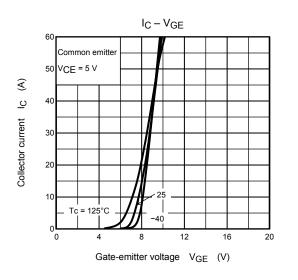
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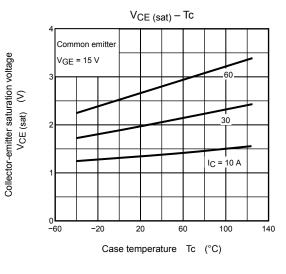




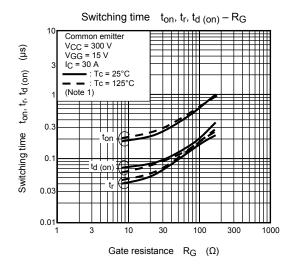


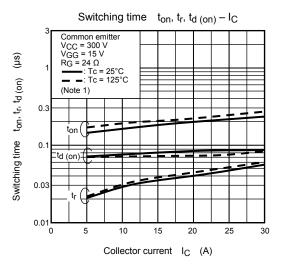


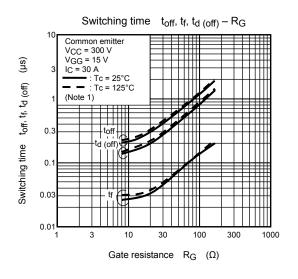


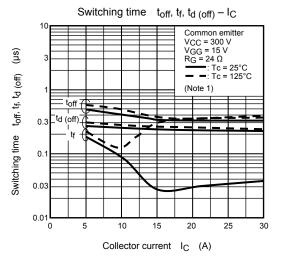


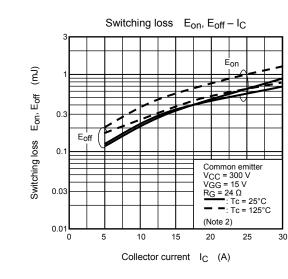
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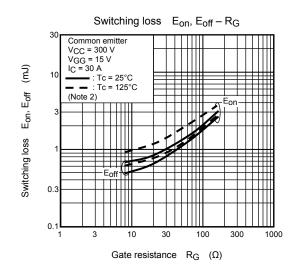




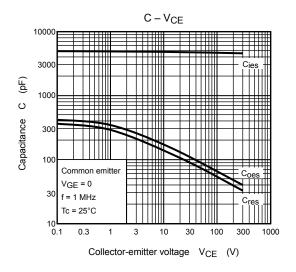


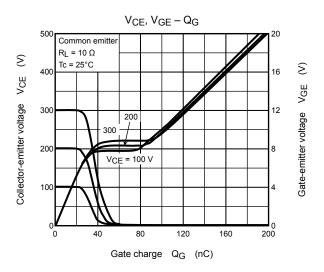




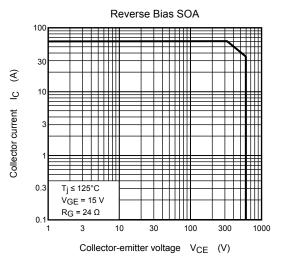


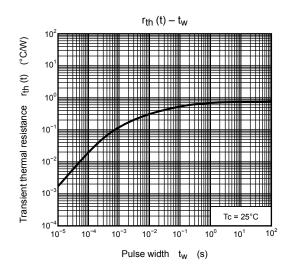
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Safe Operating Area 100 IC max (pulsed)\* IC max (continuous) 30 100 E 10 <u>ں</u> DC operation Collector current Single pulse  $Tc = 25^{\circ}C$ Curves must be derated linearly 0.3 with increase in 0 ms temperature. 0.1 3 30 300 10 1000 100 Collector-emitter voltage V<sub>CE</sub> (V)





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